# **CE** CHENYI ELECTRONICS

## KBPC10005 THRU KBPC1010

## SINGLE PHASE SILICON BRIDGE RECTIFIER

Voltage: 50 TO 1000V CURRENT:10A

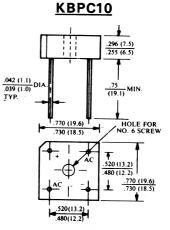
### FEATURES

Surge overload rating: 200A peak

High case dielectric strength

### **MECHANICAL DATA**

- . Terminal: Plated leads solderable per
  - MIL-STD 202E, method 208C
- . Case: UL-94 Class V-0 recognized Flame Retardant Epoxy
- . Polarity: Polarity symbol marked on body
- . Mounting : Hole thru for #6 screw



Dimensions in inches and (millimeters)

TA

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60HZ, resistive or inductive load rating at 25  $^{\circ}\!C$  , unless otherwise stated,

	SYMBOL	KBPC 10005	KBPC 1001	KBPC 1002	KBPC 1004	KBPC 1006	KBPC 1008	KBPC 1010	units
Maximum Recurrent Peak Reverse Voltage	Vrrm	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	Vrms	35	70	140	280	420	560	700	V
Maximum DC blocking Voltage	Vdc	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Tc=50 °C		10.0							А
current at Ta=25 °C Ta=50 °C	lf(av)	6.0							А
Peak Forward Surge Current 8.3ms single									
half sine-wave superimposed on rated load	lfsm	200							А
Maximum Instantaneous Forward Voltage at									
forward current 5.0A DC	Vf	1.1							V
Maximum DC Reverse Voltage Ta=25 °C		10.0							μA
at rated DC blocking voltage Ta=100 $^{\circ}\mathbf{C}$	Ir	200							μ <sub>A</sub>
Operating Temperature Range	Tj	-55 to +125							°C
Storage and operation Junction Temperature	Tstg	-55 to +150							°C

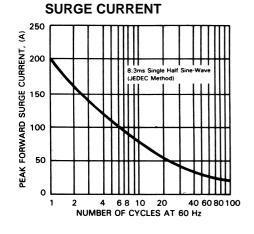


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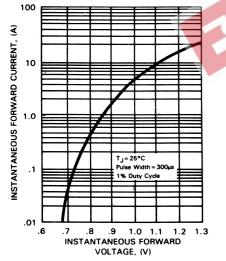
## **RATINGS AND CHARACTERISTIC CURVES KBPC10005 THRU KBPC1010**

#### FIG.1-MAXIMUM NON-REPETITIVE FORWARD

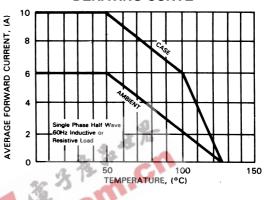


## FIG.3-TYPICAL INSTANTANEOUS

FORWARD CHARACTERISTICS



### FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE



### FIG.4-TYPICAL REVERSE CHARACTERISTICS

